

## 3 V, 2.9 GHz SILICON MMIC MEDIUM OUTPUT POWER AMPLIFIER FOR MOBILE COMMUNICATIONS

### DESCRIPTION

The μPC8182TB is a silicon monolithic integrated circuit designed as amplifier for mobile communications. This IC operates at 3 V. The medium output power is suitable for RF-TX of mobile communications system.

This IC is manufactured using our 30 GHz  $f_{max}$  UHS0 (Ultra High Speed Process) silicon bipolar process. This process uses direct silicon nitride passivation film and gold electrodes. These materials can protect the chip surface from pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

### FEATURES

- Supply voltage:  $V_{CC} = 2.7$  to  $3.3$  V
- Circuit current:  $I_{CC} = 30$  mA TYP. @  $V_{CC} = 3.0$  V
- Medium output power:  $P_{O(1dB)} = +9.5$  dBm TYP. @  $f = 0.9$  GHz  
 $P_{O(1dB)} = +9.0$  dBm TYP. @  $f = 1.9$  GHz  
 $P_{O(1dB)} = +8.0$  dBm TYP. @  $f = 2.4$  GHz
- Power gain:  $G_P = 21.5$  dB TYP. @  $f = 0.9$  GHz  
 $G_P = 20.5$  dB TYP. @  $f = 1.9$  GHz  
 $G_P = 20.5$  dB TYP. @  $f = 2.4$  GHz
- Upper limit operating frequency:  $f_u = 2.9$  GHz TYP. @ 3 dB bandwidth
- High-density surface mounting: 6-pin super minimold package ( $2.0 \times 1.25 \times 0.9$  mm)

### APPLICATION

- Buffer amplifiers on 1.9 to 2.4 GHz mobile communications system

### ORDERING INFORMATION (Solder Contains Lead)

| Part Number  | Package              | Marking | Supplying Form  |
|--------------|----------------------|---------|---|
| μPC8182TB-E3 | 6-pin super minimold | C3F     | <ul style="list-style-type: none"> <li>• Embossed tape 8 mm wide</li> <li>• Pin 1, 2, 3 face the perforation side of the tape</li> <li>• Qty 3 kpcs/reel</li> </ul> |

**Remark** To order evaluation samples, contact you're nearby sales office. Part number for sample order:  
μPC8182TB

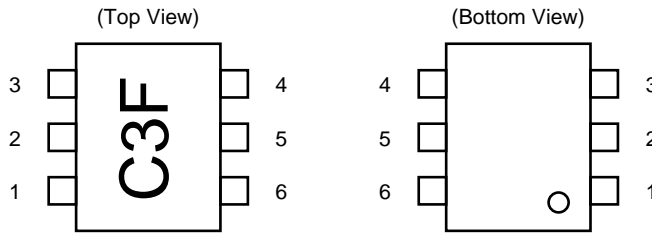
### ORDERING INFORMATION (Pb-Free)

| Part Number      | Package              | Marking | Supplying Form  |
|------------------|----------------------|---------|---|
| μPC8182TB-E3-AZ* | 6-pin super minimold | C3F     | <ul style="list-style-type: none"> <li>• Embossed tape 8 mm wide</li> <li>• Pin 1, 2, 3 face the perforation side of the tape</li> <li>• Qty 3 kpcs/reel</li> </ul> |

**\*NOTE:** Please refer to the last page of this data sheet, "Compliance with EU Directives" for Pb-Free RoHS Compliance Information.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

**PIN CONNECTIONS**



| Pin No. | Pin Name        |
|---------|-----------------|
| 1       | INPUT           |
| 2       | GND             |
| 3       | GND             |
| 4       | OUTPUT          |
| 5       | GND             |
| 6       | V <sub>cc</sub> |

**PRODUCT LINE-UP (T<sub>A</sub> = +25°C, V<sub>cc</sub> = V<sub>out</sub> = 3.0 V, Z<sub>s</sub> = Z<sub>L</sub> = 50 Ω)**

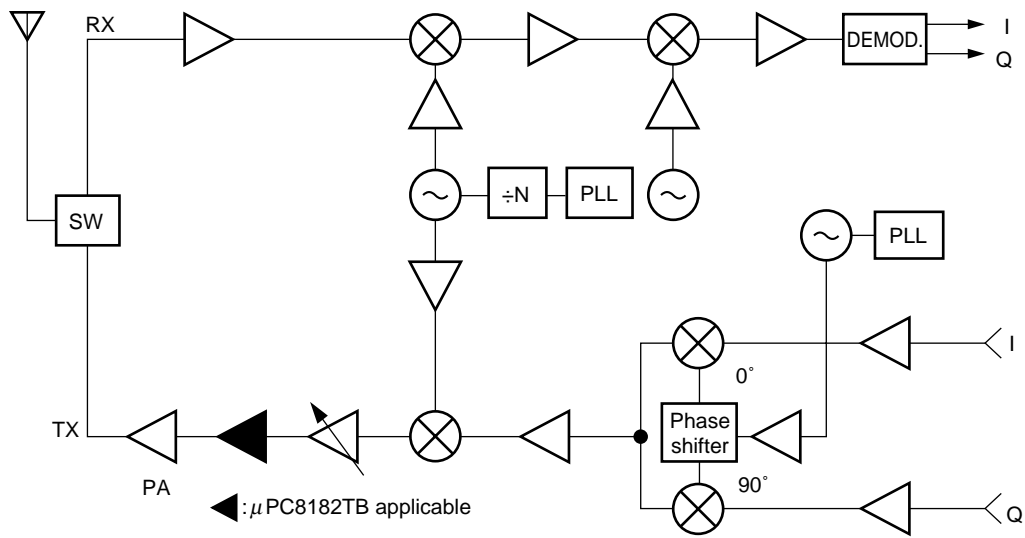
| Part No.         | f <sub>u</sub> (GHz) | P <sub>O</sub> (1 dB) (dBm)                                    | G <sub>P</sub> (dB)  | I <sub>cc</sub> (mA) | Package              | Marking |
|------------------|----------------------|--|--|----------------------|----------------------|---------|
| $\mu$ PC8182TB   | 2.9                  | +9.5 @ f = 0.9 GHz<br>+9.0 @ f = 1.9 GHz<br>+8.0 @ f = 2.4 GHz | 21.5 @ f = 0.9 GHz<br>20.5 @ f = 1.9 GHz<br>20.5 @ f = 2.4 GHz | 30.0                 | 6-pin super minimold | C3F     |
| $\mu$ PC2762T    | 2.9                  | +8.0 @ f = 0.9 GHz   | 13.0 @ f = 0.9 GHz   | 26.5                 | 6-pin minimold       | C1Z     |
| $\mu$ PC2762TB   |                      | +7.0 @ f = 1.9 GHz   | 15.5 @ f = 1.9 GHz   |                      | 6-pin super minimold |         |
| $\mu$ PC2763T    | 2.7                  | +9.5 @ f = 0.9 GHz   | 20.0 @ f = 0.9 GHz   | 27.0                 | 6-pin minimold       | C2A     |
| $\mu$ PC2763TB   |                      | +6.5 @ f = 1.9 GHz   | 21.0 @ f = 1.9 GHz   |                      | 6-pin super minimold |         |
| $\mu$ PC2771T    | 2.2                  | +11.5 @ f = 0.9 GHz  | 21.0 @ f = 0.9 GHz   | 36.0                 | 6-pin minimold       | C2H     |
| $\mu$ PC2771TB   |                      | +9.5 @ f = 1.5 GHz   | 21.0 @ f = 1.5 GHz   |                      | 6-pin super minimold |         |
| ★ $\mu$ PC8181TB | 4.0                  | +8.0 @ f = 0.9 GHz<br>+7.0 @ f = 1.9 GHz<br>+7.0 @ f = 2.4 GHz | 19.0 @ f = 0.9 GHz<br>21.0 @ f = 1.9 GHz<br>22.0 @ f = 2.4 GHz | 23.0                 | 6-pin super minimold | C3E     |

**Remark** Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

**Caution** The package size distinguishes between minimold and super minimold.

SYSTEM APPLICATION EXAMPLE

Digital cellular telephone



**Caution** The insertion point is different due to the specifications of conjunct devices.

**PIN EXPLANATION**

| Pin No.     | Pin Name | Applied Voltage (V)                                   | Pin Voltage (V) <small>Note</small> | Function and Applications  | Internal Equivalent Circuit |
|-------------|----------|---|-------------------------------------|--|-----------------------------|
| 1           | INPUT    | –   | 0.99                                | Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. A multi-feedback circuit is designed to cancel the deviations of $h_{FE}$ and resistance. This pin must be coupled to signal source with capacitor for DC cut. |                             |
| 4           | OUTPUT   | Voltage as same as $V_{CC}$ through external inductor | –                                   | Signal output pin. The inductor must be attached between $V_{CC}$ and output pins to supply current to the internal output transistors.  |                             |
| 6           | $V_{CC}$ | 2.7 to 3.3  | –                                   | Power supply pin, which biases the internal input transistor. This pin should be externally equipped with bypass capacitor to minimize its impedance.  |                             |
| 2<br>3<br>5 | GND      | 0   | –                                   | Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance difference.                     |                             |

**Note** Pin voltage is measured at  $V_{CC} = 3.0\text{ V}$ .

**ABSOLUTE MAXIMUM RATINGS**

| Parameter                     | Symbol           | Test Conditions                         | Ratings     | Unit |
|-------------------------------|------------------|---|-------------|------|
| Supply Voltage                | V <sub>CC</sub>  | T <sub>A</sub> = +25°C, pin 4 and pin 6 | 3.6         | V    |
| Total Circuit Current         | I <sub>CC</sub>  | T <sub>A</sub> = +25°C                  | 60          | mA   |
| Power Dissipation             | P <sub>D</sub>   | T <sub>A</sub> = +85°C <b>Note</b>      | 270         | mW   |
| Operating Ambient Temperature | T <sub>A</sub>   |   | -40 to +85  | °C   |
| Storage Temperature           | T <sub>stg</sub> |   | -55 to +150 | °C   |
| Input Power                   | P <sub>in</sub>  | T <sub>A</sub> = +25°C                  | +10         | dBm  |

**Note** Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

**RECOMMENDED OPERATING RANGE**

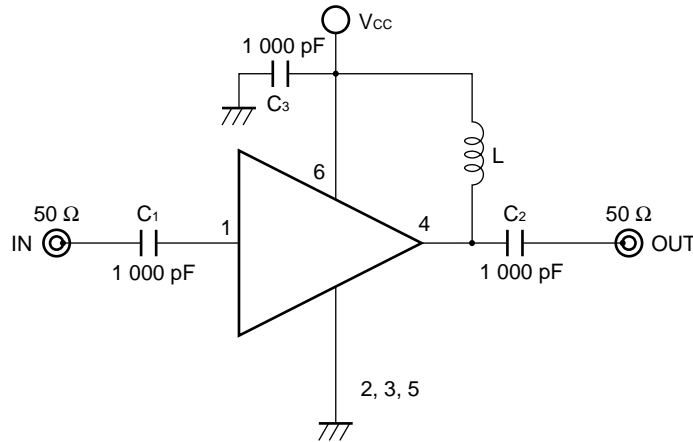
| Parameter                     | Symbol          | MIN. | TYP. | MAX. | Unit | Remarks  |
|-------------------------------|-----------------|------|------|------|------|--|
| Supply Voltage                | V <sub>CC</sub> | 2.7  | 3.0  | 3.3  | V    | Same voltage should be applied to pin 4 and pin 6. |
| Operating Ambient Temperature | T <sub>A</sub>  | -40  | +25  | +85  | °C   | -  |

**ELECTRICAL CHARACTERISTICS**

( $T_A = +25^\circ\text{C}$ ,  $V_{CC} = V_{out} = 3.0\text{ V}$ ,  $Z_s = Z_L = 50\ \Omega$ , unless otherwise specified)

| Parameter                          | Symbol       | Test Conditions   | MIN.                 | TYP.                    | MAX.                 | Unit |
|------------------------------------|--------------|---|----------------------|-------------------------|----------------------|------|
| Circuit Current                    | $I_{CC}$     | No signal   | –                    | 30.0                    | 38.0                 | mA   |
| Power Gain                         | $G_P$        | f = 0.9 GHz<br>f = 1.9 GHz<br>f = 2.4 GHz   | 19.0<br>18.0<br>18.0 | 21.5<br>20.5<br>20.5    | 25.0<br>24.0<br>24.0 | dB   |
| Noise Figure                       | NF           | f = 0.9 GHz<br>f = 1.9 GHz<br>f = 2.4 GHz   | –<br>–<br>–          | 4.5<br>4.5<br>5.0       | 6.0<br>6.0<br>6.5    | dB   |
| Upper Limit Operating Frequency    | $f_u$        | 3 dB down below from gain at f = 0.1 GHz  | 2.6                  | 2.9                     | –                    | GHz  |
| Isolation                          | ISL          | f = 0.9 GHz<br>f = 1.9 GHz<br>f = 2.4 GHz   | 28<br>27<br>26       | 33<br>32<br>31          | –<br>–<br>–          | dB   |
| Input Return Loss                  | $RL_{in}$    | f = 0.9 GHz<br>f = 1.9 GHz<br>f = 2.4 GHz   | 5<br>7<br>9          | 8<br>10<br>12           | –<br>–<br>–          | dB   |
| Output Return Loss                 | $RL_{out}$   | f = 0.9 GHz<br>f = 1.9 GHz<br>f = 2.4 GHz   | 7<br>8<br>11         | 10<br>11<br>14          | –<br>–<br>–          | dB   |
| Gain 1 dB Compression Output Power | $P_{O(1dB)}$ | f = 0.9 GHz<br>f = 1.9 GHz<br>f = 2.4 GHz   | +7.0<br>+6.5<br>+5.5 | +9.5<br>+9.0<br>+8.0    | –<br>–<br>–          | dBm  |
| Saturated Output Power             | $P_{O(sat)}$ | f = 0.9 GHz, $P_{in} = -5\text{ dBm}$<br>f = 1.9 GHz, $P_{in} = -5\text{ dBm}$<br>f = 2.4 GHz, $P_{in} = -5\text{ dBm}$ | –<br>–<br>–          | +11.0<br>+10.5<br>+10.0 | –<br>–<br>–          | dBm  |

**TEST CIRCUITS**



**COMPONENTS OF TEST CIRCUIT FOR MEASURING ELECTRICAL CHARACTERISTICS**

|                                 | Type      | Value    |
|---------------------------------|-----------|----------|
| C <sub>1</sub> , C <sub>2</sub> | Bias Tee  | 1 000 pF |
| C <sub>3</sub>                  | Capacitor | 1 000 pF |
| L                               | Bias Tee  | 1 000 nH |

**EXAMPLE OF ACTUAL APPLICATION COMPONENTS**

|                                  | Type           | Value    | Operating Frequency |
|----------------------------------|----------------|----------|---------------------|
| C <sub>1</sub> to C <sub>3</sub> | Chip capacitor | 1 000 pF | 100 MHz or higher   |
| L                                | Chip inductor  | 100 nH   | 100 MHz or higher   |
|                                  |                | 10 nH    | 2.0 GHz or higher   |

**INDUCTOR FOR THE OUTPUT PIN**

The internal output transistor of this IC consumes 20 mA, to output medium power. To supply current for output transistor, connect an inductor between the Vcc pin (pin 6) and output pin (pin 4). Select large value inductance, as listed above.

The inductor has both DC and AC effects. In terms of DC, the inductor biases the output transistor with minimum voltage drop to output enable high level. In terms of AC, the inductor makes output-port-impedance higher to get enough gain. In this case, large inductance and Q is suitable.

For above reason, select an inductance of 100 Ω or over impedance in the operating frequency. The gain is a peak in the operating frequency band, and suppressed at lower frequencies.

The recommendable inductance can be chosen from example of actual application components list as shown above.

**CAPACITORS FOR THE VCC, INPUT, AND OUTPUT PINS**

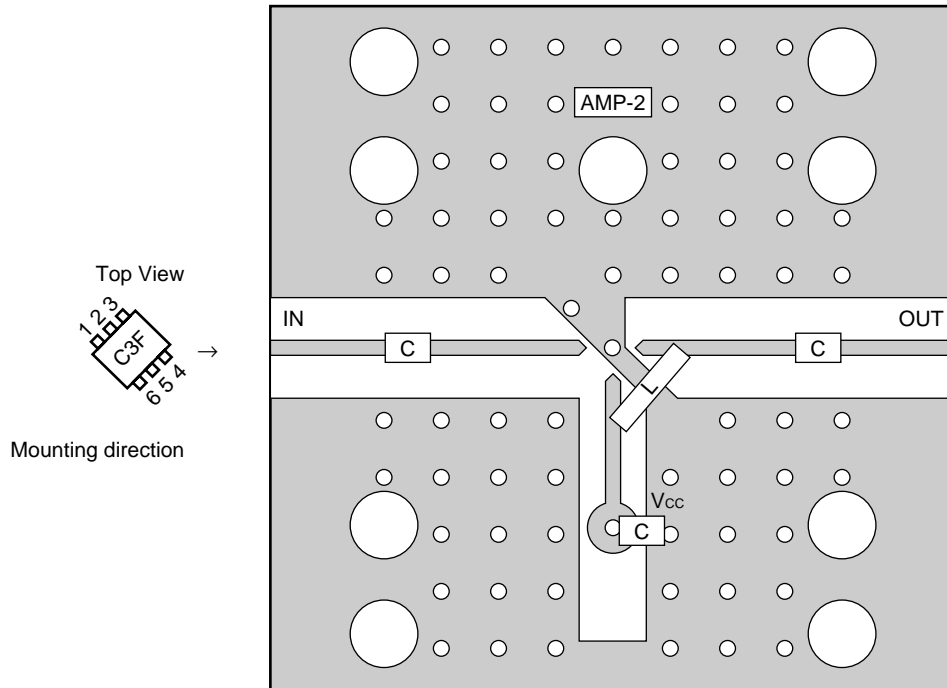
Capacitors of 1 000 pF are recommendable as the bypass capacitor for the Vcc pin and the coupling capacitors for the input and output pins.

The bypass capacitor connected to the Vcc pin is used to minimize ground impedance of Vcc pin. So, stable bias can be supplied against Vcc fluctuation.

The coupling capacitors, connected to the input and output pins, are used to cut the DC and minimize RF serial impedance. Their capacitance are therefore selected as lower impedance against a 50 Ω load. The capacitors thus perform as high pass filters, suppressing low frequencies to DC.

To obtain a flat gain from 100 MHz upwards, 1 000 pF capacitors are used in the test circuit. In the case of under 10 MHz operation, increase the value of coupling capacitor such as 10 000 pF. Because the coupling capacitors are determined by equation,  $C = 1/(2\pi Rfc)$ .

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

|   | Value          |
|---|----------------|
| C | 1 000 pF       |
| L | Example: 10 nH |

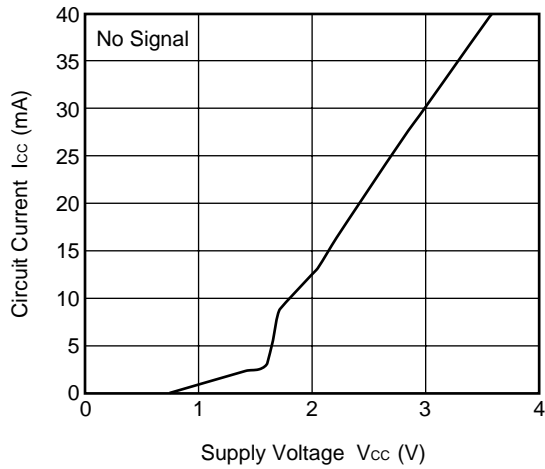
Notes

1. 30 × 30 × 0.4 mm double-sided copper-clad polyimide board.
2. Back side: GND pattern
3. Solder plated on pattern
4. ○ ○ : Through holes

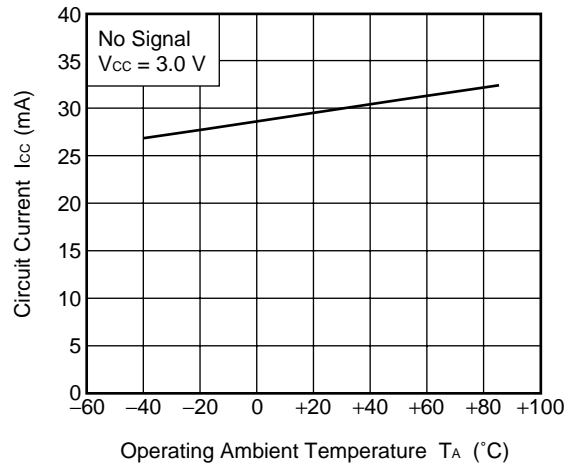


TYPICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ , unless otherwise specified)

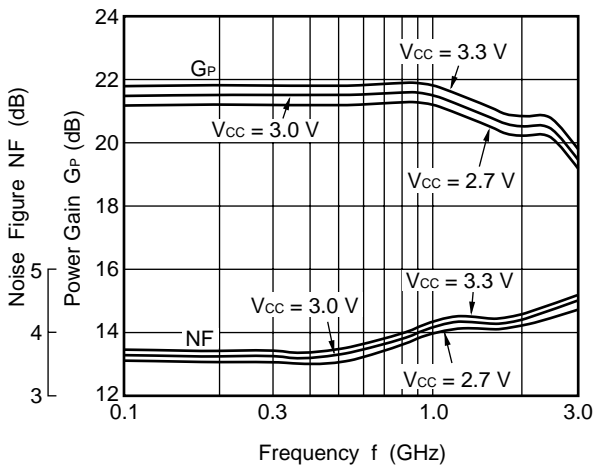
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



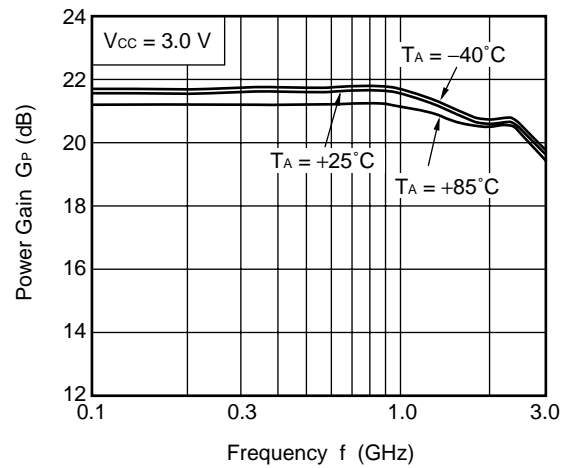
CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



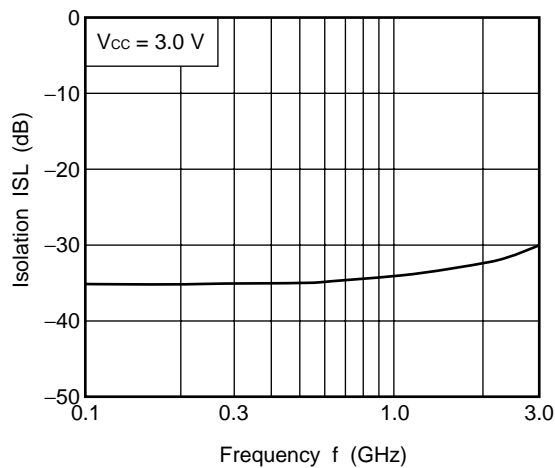
NOISE FIGURE, POWER GAIN vs. FREQUENCY



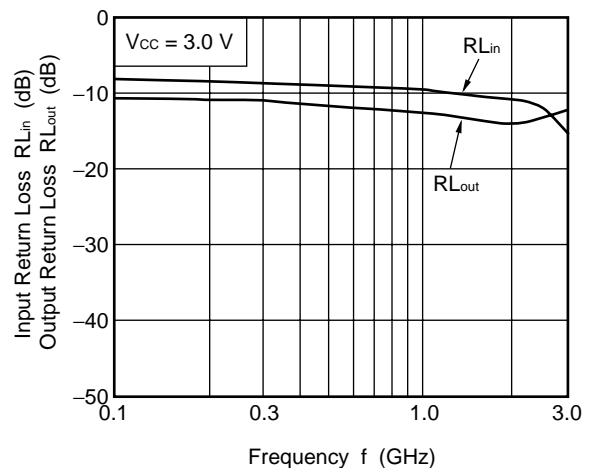
POWER GAIN vs. FREQUENCY



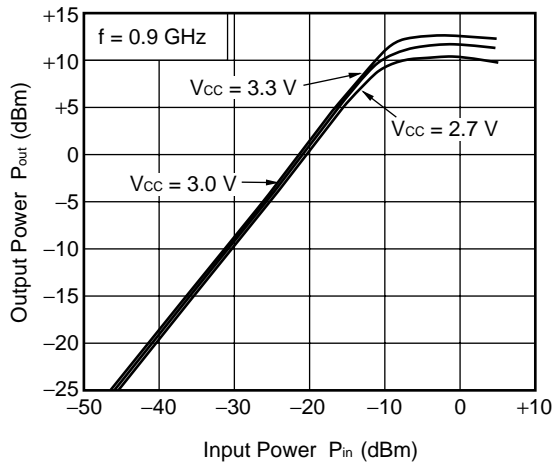
ISOLATION vs. FREQUENCY



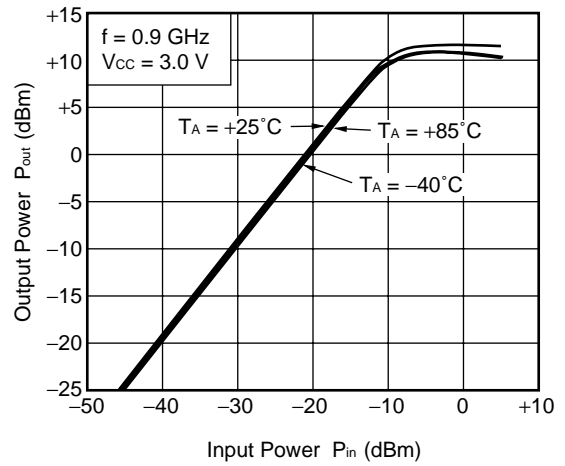
INPUT RETURN LOSS, OUTPUT RETURN LOSS vs. FREQUENCY



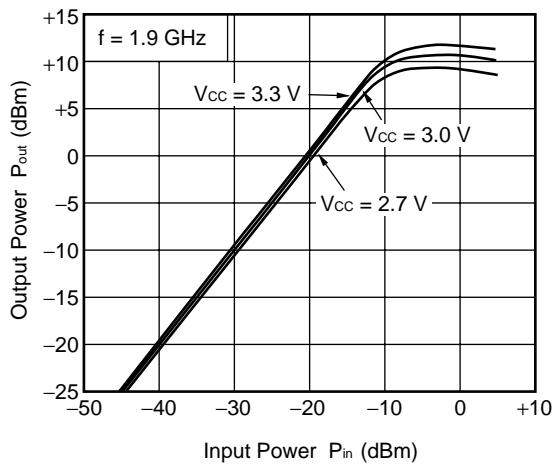
OUTPUT POWER vs. INPUT POWER



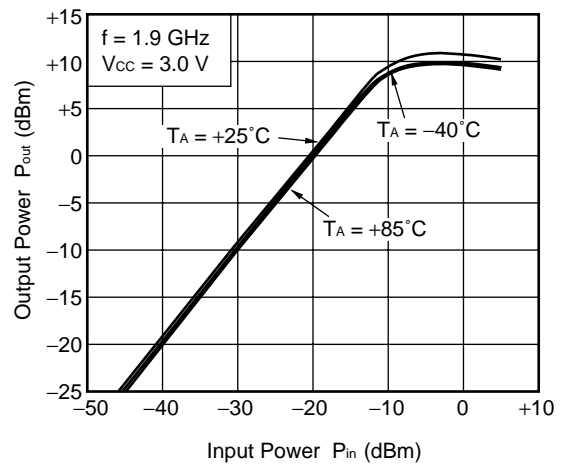
OUTPUT POWER vs. INPUT POWER



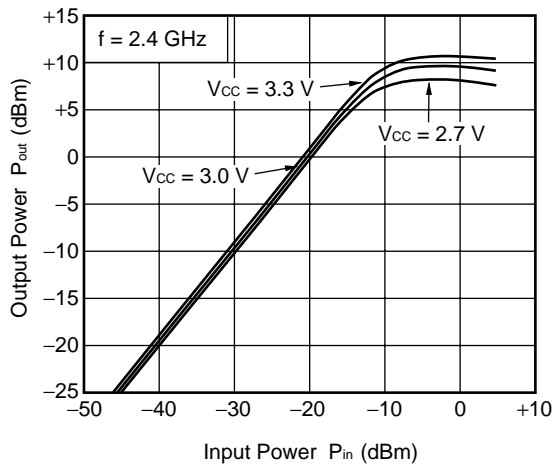
OUTPUT POWER vs. INPUT POWER



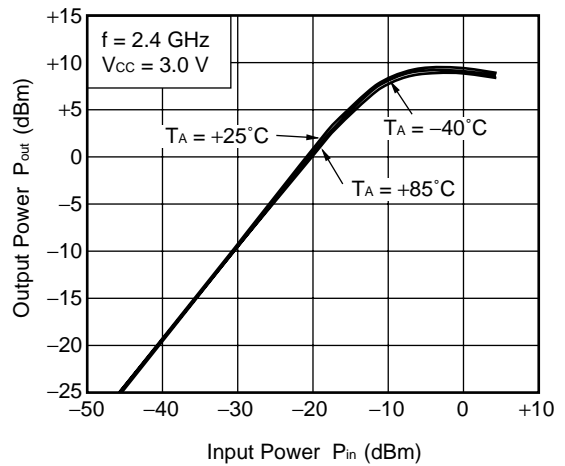
OUTPUT POWER vs. INPUT POWER



OUTPUT POWER vs. INPUT POWER

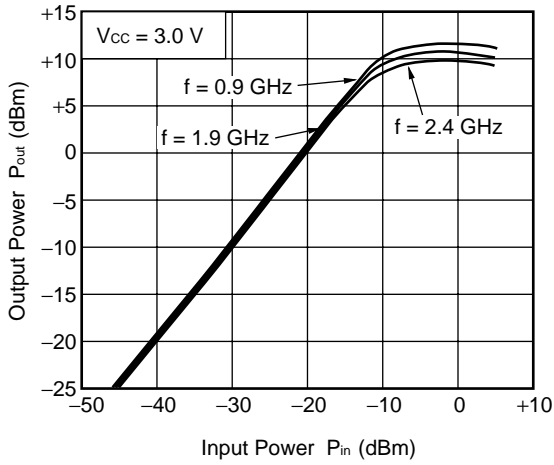


OUTPUT POWER vs. INPUT POWER

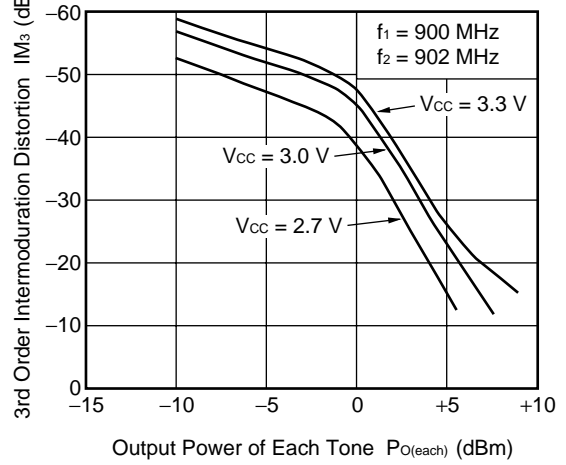


★

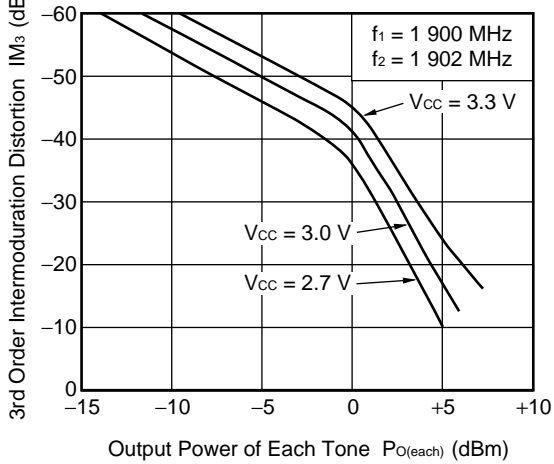
OUTPUT POWER vs. INPUT POWER



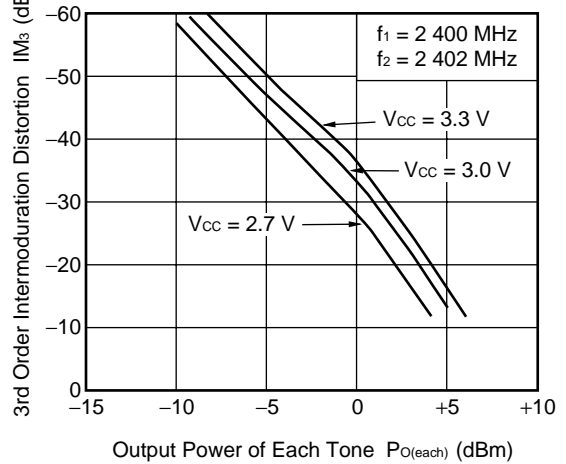
3RD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE



3RD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE



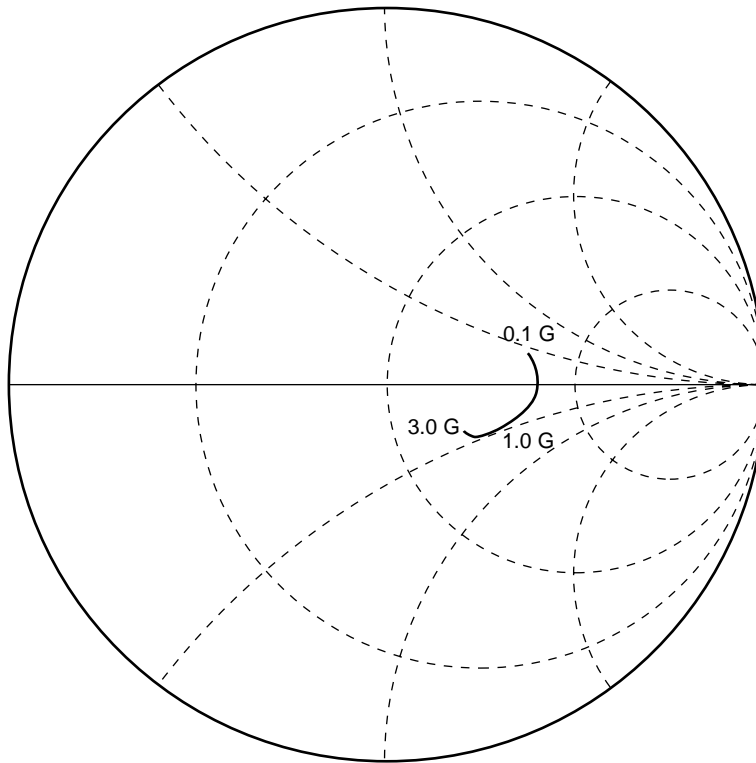
3RD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE



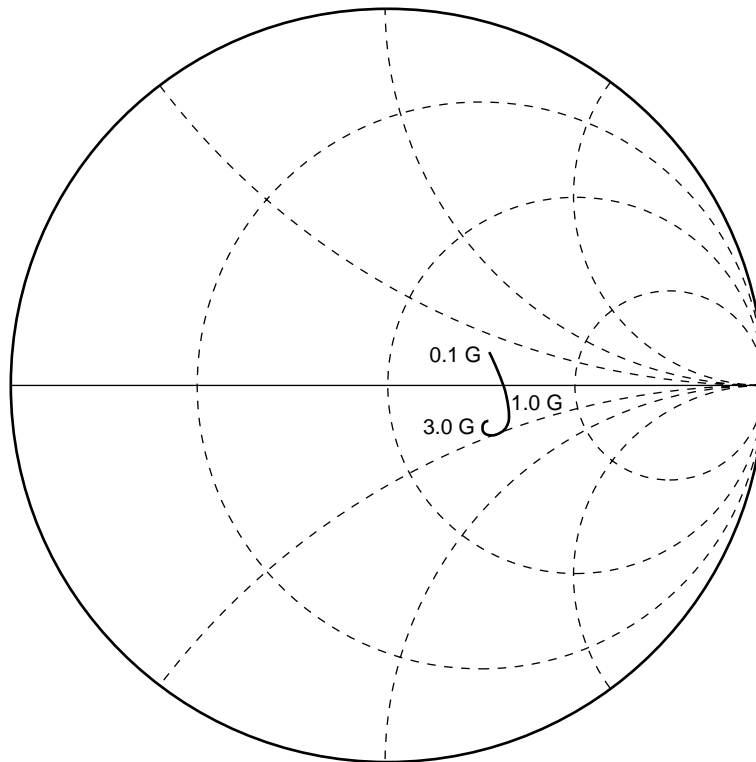
**Remark** The graphs indicate nominal characteristics.

SMITH CHART ( $V_{CC} = V_{out} = 3.0\text{ V}$ )

S<sub>11</sub>-FREQUENCY



S<sub>22</sub>-FREQUENCY



**★ S-PARAMETERS**

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

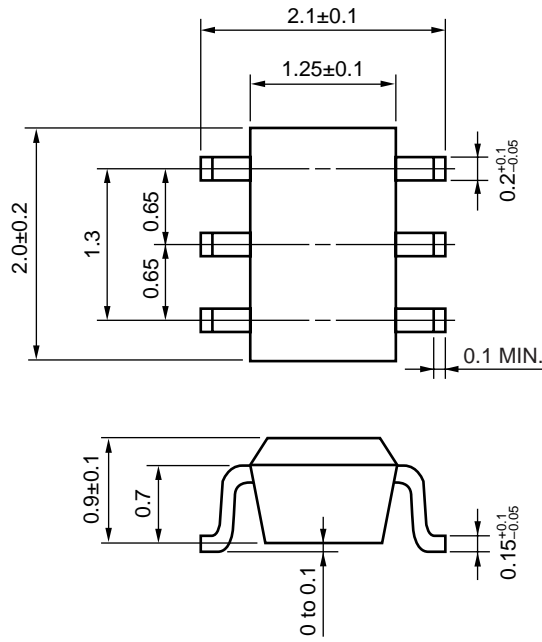
Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

URL <http://www.csd-nec.com/>

PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



**NOTES ON CORRECT USE**

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).  
All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to the V<sub>cc</sub> pin.
- (4) The inductor must be attached between V<sub>cc</sub> and output pins. The inductance value should be determined in accordance with desired frequency.
- (5) The DC cut capacitor must be attached to input and output pin.

**RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

| Soldering Method | Soldering Conditions  | Condition Symbol |
|------------------|---|------------------|
| Infrared Reflow  | Peak temperature (package surface temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Time at temperature of 220°C or higher : 60 seconds or less<br>Preheating time at 120 to 180°C : 120±30 seconds<br>Maximum number of reflow processes : 3 times<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | IR260            |
| VPS              | Peak temperature (package surface temperature) : 215°C or below<br>Time at temperature of 200°C or higher : 25 to 40 seconds<br>Preheating time at 120 to 150°C : 30 to 60 seconds<br>Maximum number of reflow processes : 3 times<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below  | VP215            |
| Wave Soldering   | Peak temperature (molten solder temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Preheating temperature (package surface temperature) : 120°C or below<br>Maximum number of flow processes : 1 time<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below  | WS260            |
| Partial Heating  | Peak temperature (pin temperature) : 350°C or below<br>Soldering time (per side of device) : 3 seconds or less<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below  | HS350            |

**Caution Do not use different soldering methods together (except for partial heating).**

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL’s understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

| Restricted Substance per RoHS | Concentration Limit per RoHS (values are not yet fixed) | Concentration contained in CEL devices |     |
|-------------------------------|---|--|-----|
|                               |   | -A                                     | -AZ |
| Lead (Pb)                     | < 1000 PPM  | Not Detected                           | (*) |
| Mercury                       | < 1000 PPM  | Not Detected                           |     |
| Cadmium                       | < 100 PPM   | Not Detected                           |     |
| Hexavalent Chromium           | < 1000 PPM  | Not Detected                           |     |
| PBB                           | < 1000 PPM  | Not Detected                           |     |
| PBDE                          | < 1000 PPM  | Not Detected                           |     |

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

**Important Information and Disclaimer:** Information provided by CEL on its website or in other communications concerning the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL’s liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.